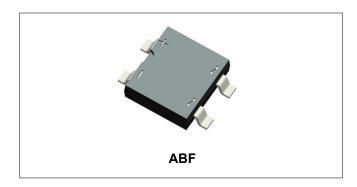


RoHS



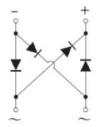
ABF2U THRU ABF10U SINGLE PHASE 1.0AMP SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER



Features

- Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Designed for surface mount application
- Plastic material-UL flammability 94V-0
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: SOPA-4, Molded plastic ABF
- Terminals: Plated leads solderable per MIL-STD-202, Method 208
- Polarity: Polarity symbols marked on case
- Mounting Position: Any

Maximum Ratings@TA=25°C unless otherwise specified

Single Phase half wave 60Hz, resistive or inductive load. For capacitive load current derate by 20%.

Characteristic	Symbol	ABF2U	ABF4U	ABF6U	ABF8U	ABF10U	Units
Maximum repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	
RMS Reverse Voltage	V _{R(RMS)}	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	200	400	600	800	1000	
Average Rectified Output Current @T _C = 100°C	I _{F(AV)}	1.0				V	
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	35				А	
Rating for fusing (t<8.3ms)	l²t	5.08				A ² s	

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Electrical Characteristics:

Characteristic	Symbol	ABF2U	ABF4U	ABF6U	ABF8U	ABF10U	Units
Forward voltage per element @ I _F = 0.5A @ I _F = 1.0A	VF			0.95 1.0			V
Maximum DC reverse current $T_A = 25^{\circ}C$ at rated DC blocking voltage $T_A = 125^{\circ}C$	I _R			5 200			μA

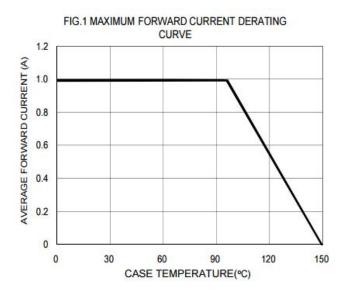
 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

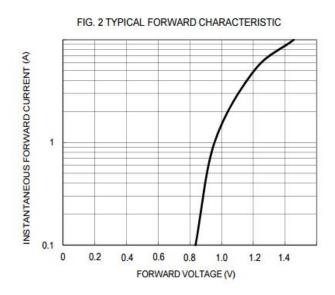
Thermal-Mechanical Specifications:

Characteristic	Symbol	ABF2U	ABF4U	ABF6U	ABF8U	ABF10U	Units
Typical thermal resistance per leg (Note 1)	R _{0JL} R _{0JA}	62.5 25		°C/W			
Operating and storage temperature range	T _J ,T _{STG}	-55 to +150			°C		

Note: 1. Thermal resistance form junction to ambient and junction to lead mounted on P.C.B. with 0.2X0.2"(5X5mm) copper pads.

Ratings and Characteristics Curves





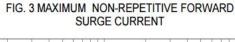
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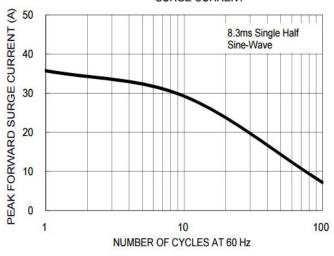


FIG. 4 TYPICAL REVERSE CHARACTERISTICS

100

TA=125°C

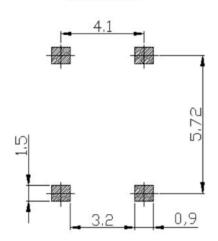
TA=75°C

TA=25°C

0 20 40 60 80 100 120 140

PERCENT OF RATED PEAK REVERSE VOLTAGE(%)

PAD LAYOUT

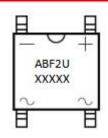


Ordering Information

Device	Package	Shipping
ABF2U THRU	ABF	5000pcs / reel
ABF10U		· ·

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

ABF2U = Type Number
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

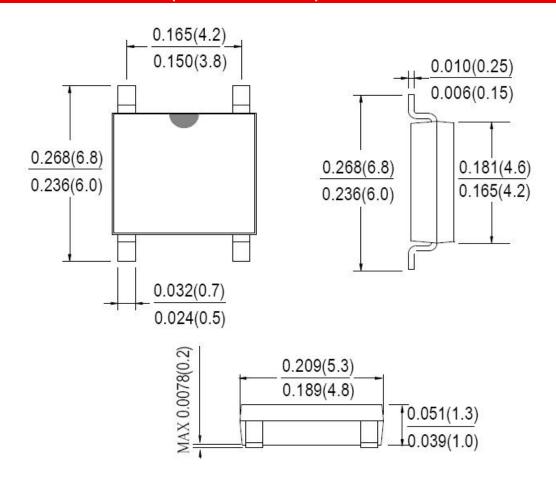
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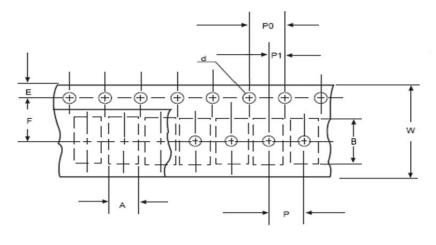




Mechanical Dimensions ABF(Inches/Millimeters)



Carrier Tape & Reel Specification ABF



SYMBOL	Millimet	ers		
OTMBOL	Min.			
Α	5.00	5.40		
В	6.40	6.80		
d	1.40	1.60		
E	1.40	1.60		
F	5.55	5.75		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
W	11.50	12.50		

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